

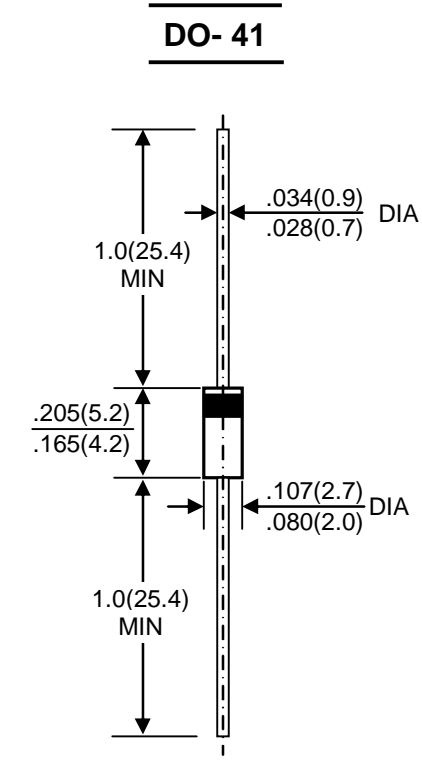
<b>HIGH EFFICIENCY (ULTRA FAST) RECTIFIERS</b>	<b>REVERSE VOLTAGE - 50 to 1000 Volts</b> <b>FORWARD CURRENT - 1.0 Ampere</b>
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### FEATURES

- Low cost
- Diffused junction
- Ultra fast switching for high efficiency
- Low reverse leakage current
- Low forward voltage drop
- High current capability
- The plastic material carries UL recognition 94V-0

### MECHANICAL DATA

- Case: JEDEC DO-41 molded plastic
- Polarity: Color band denotes cathode
- Weight: 0.012 ounces , 0.34 grams
- Mounting position: Any



Dimensions in inches and (millimeters)

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.  
 Single phase, half wave ,60Hz, resistive or inductive load.  
 For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	HER101	HER102	HER103	HER104	HER105	HER106	HER107	HER108	UNIT	
		UF4001	UF4002	UF4003	UF4004	UF4005	UF4006	UF4007	UF4008		
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	300	400	600	800	1000	V	
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	140	210	280	420	560	700	V	
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	300	400	600	800	1000	V	
Maximum Average Forward Rectified Current @T <sub>A</sub> =55 °C	I <sub>(AV)</sub>	1.0								A	
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed on Rated Load(JEDEC Method)	I <sub>FSM</sub>	30								A	
Peak Forward Voltage at 1.0A DC	V <sub>F</sub>	1.0			1.3		1.7			V	
Maximum DC Reverse Current @T <sub>J</sub> =25°C at Rated DC Blocking Voltage @T <sub>J</sub> =100°C	I <sub>R</sub>	5.0								μA	
		100									
Maximum Reverse Recovery Time(Note 1)	T <sub>RR</sub>	50					75				nS
Typical Junction Capacitance (Note2)	C <sub>J</sub>	20					10				pF
Typical Thermal Resistance (Note3)	R <sub>θJA</sub>	25								°C/W	
Operating Temperature Range	T <sub>J</sub>	-55 to +150								°C	
Storage Temperature Range	T <sub>STG</sub>	-55 to +150								°C	

NOTES: 1.Measured with I<sub>F</sub>=0.5A,I<sub>R</sub>=1A,I<sub>RR</sub>=0.25A.  
 2.Measured at 1.0 MHz and applied reverse voltage of 4.0V DC  
 3.Thermal resistance junction to ambient.

FIG. 1 – FORWARD CURRENT DERATING CURVE

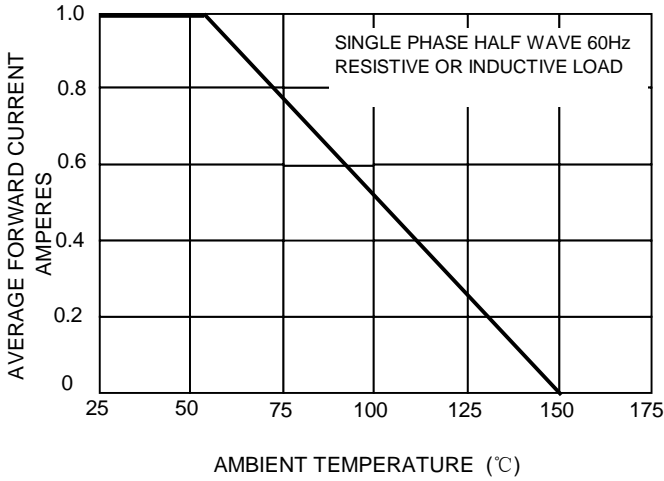


FIG. 2 – MAXIMUM NON-REPETITIVE SURGE CURRENT

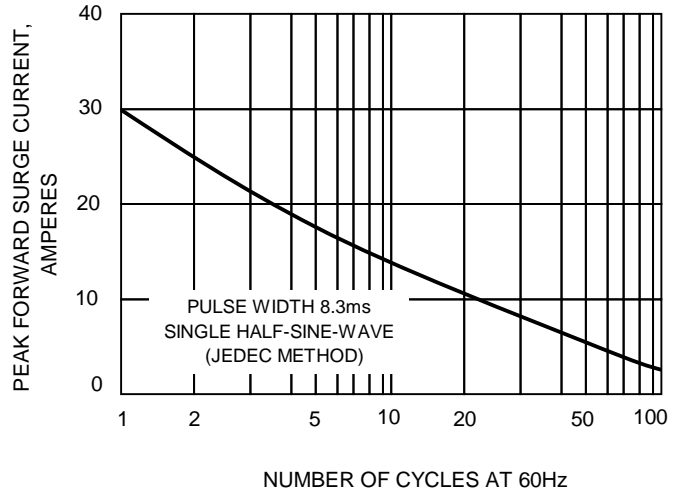


FIG.3 – TYPICAL JUNCTION CAPACITANCE

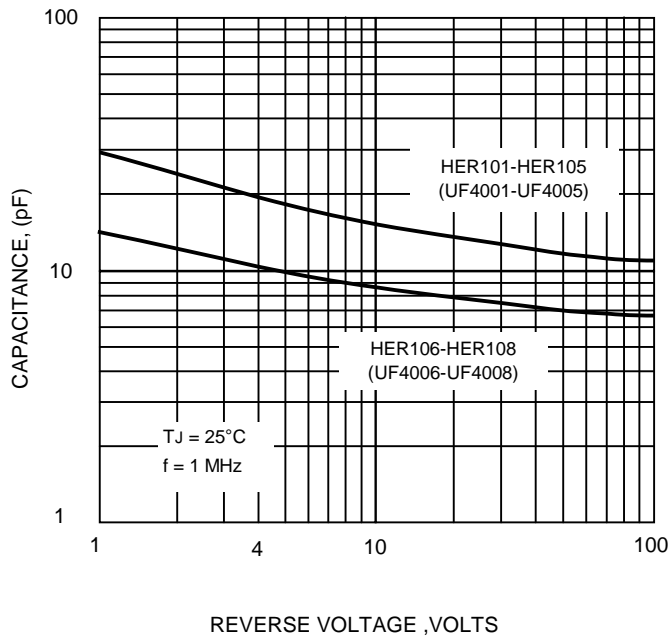


FIG.4-TYPICAL FORWARD CHARACTERISTICS

